2-W STEREO AUDIO POWER AMPLIFIER WITH DirectPath™ STEREO HEADPHONE DRIVE AND REGULATOR

FEATURES

- **Microsoft™Windows Vista™ Compliant**
- **Fully Differential Architecture and High PSRR Provide Excellent RF Rectification Immunity**
- **2-W, 10% THD+N Into 4-Ω Speakers and 85-mW, 1% THD+N Into 16-Ω Headphones From 5-V Supply**
- **DirectPath™ Headphone Amplifier Eliminates Output Capacitors** (1)
- **Internal 4-Step Speaker Gain Control: 6, 10, 15.6, 21.6 dB and Fixed –1.5-V/V Headphone**
- **4.75-V Low Dropout Regulator for CODEC**
- **Independent Shutdown Controls for Speaker, Headphone Amplifier, and Low Dropout Regulator (LDO)**
- **Output Short-Circuit and Thermal Protection**

APPLICATIONS

- **Notebook Computers**
- **Portable DVD**

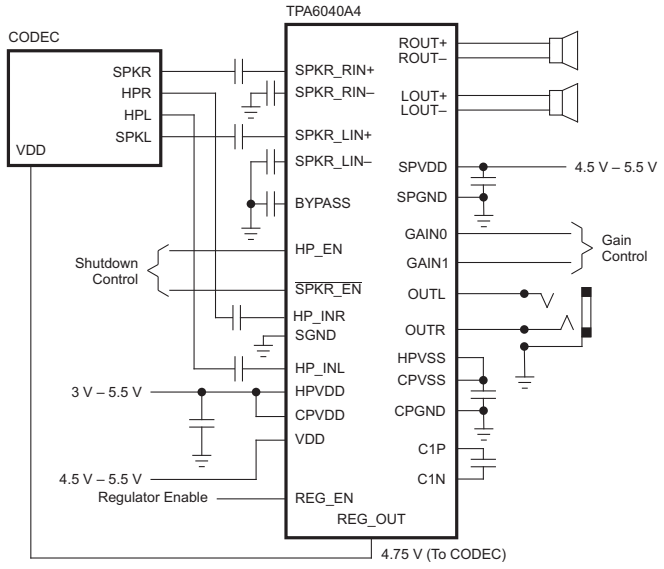
(1) US Patent Number 5289137

DESCRIPTION

The TPA6040A4 is a stereo audio power amplifier and DirectPath™ headphone amplifier in a thermally enhanced, space-saving, 32-pin QFN package. The speaker amplifier is capable of driving 2 W per channel continuously into 4-Ω loads at 5 V. The headphone amplifier achieves a minimum of 85 mW at 1% THD+N from a 5-V supply. A built-in internal 4-step gain control for the speaker amplifier and a fixed –1.5 V/V gain for the headphone amplifier minimizes external components needed.

Independent shutdown control and dedicated inputs for the speaker and headphone allow the TPA6040A4 to simultaneously drive both headphones and internal speakers. Differential inputs to the speaker amplifiers offer superior power-supply and common-mode noise rejection.

SIMPLIFIED APPLICATION CIRCUIT



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

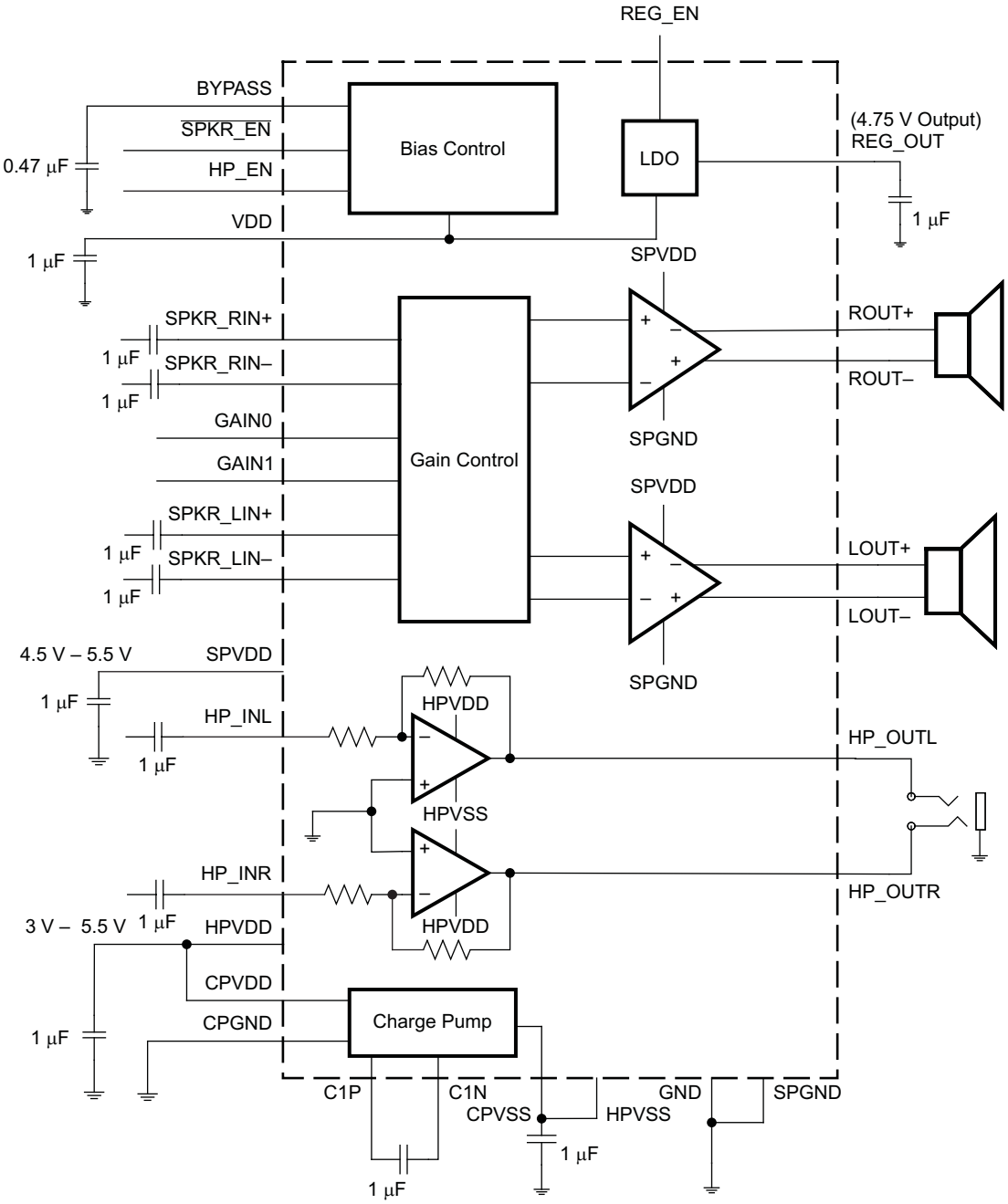
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These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

Functional Block Diagram

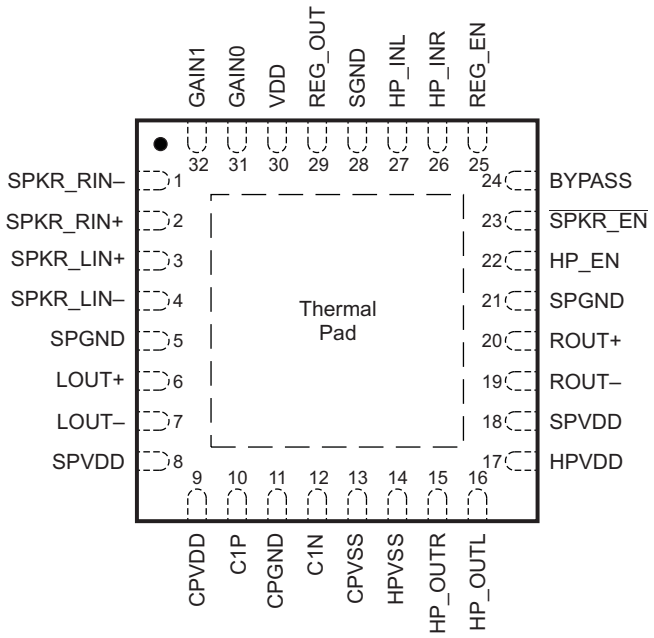


AVAILABLE PACKAGE OPTIONS

T_A	PACKAGED DEVICE(1)(2) 32-Pin QFN (RHB)	SYMBOL
–40°C to 85°C	TPA6040A4RHB	RHB

(1) The RHB package is available taped and reeled. To order a taped and reeled part, add the suffix R to the part number (e.g., TPA6040A4RHBR).
(2) For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI website at www.ti.com.

TPA6040A4RHB
(TOP VIEW)



TERMINAL FUNCTIONS

TERMINAL		I/O/P	DESCRIPTION
NAME	NO.		
SPKR_RIN–	1	I	Right-channel negative differential audio input for speaker amplifier
SPKR_RIN+	2	I	Right-channel positive differential audio input for speaker amplifier
SPKR_LIN+	3	I	Left-channel positive differential audio input for speaker amplifier
SPKR_LIN–	4	I	Left-channel negative differential audio input for speaker amplifier
SPGND	5, 21	P	Speaker power ground
LOUT+	6	O	Left-channel positive audio output
LOUT–	7	O	Left-channel negative audio output
SPVDD	8, 18	P	Supply voltage terminal for speaker amplifier
CPVDD	9	P	Charge pump positive supply, connect to HPVDD via star connection
C1P	10	I/O	Charge pump flying capacitor positive terminal
CPGND	11	P	Charge pump ground
C1N	12	I/O	Charge pump flying capacitor negative terminal
CPVSS	13	P	Charge pump output (negative supply for headphone amplifier), connect to HPVSS
HPVSS	14	P	Headphone amplifier negative supply, connect to CPVSS
HP_OUTR	15	O	Right-channel capacitor-free headphone output
HP_OUTL	16	O	Left-channel capacitor-free headphone output
HPVDD	17	P	Headphone amplifier supply voltage, connect to CPVDD
ROUT–	19	O	Right-channel negative audio output

TERMINAL FUNCTIONS (continued)

TERMINAL		I/O/P	DESCRIPTION
NAME	NO.		
ROUT+	20	O	Right-channel positive audio output
HP_EN	22	I	Headphone channel enable logic input; active high enable. HIGH=ENABLE.
$\overline{\text{SPKR_EN}}$	23	I	Speaker channel enable logic input; active low enable. LOW=ENABLE.
BYPASS	24	P	Common-mode bias voltage for speaker preamplifiers
REG_EN	25	I	Enable pin (Active HIGH) for turning on/off LDO. HIGH=ENABLE
HP_INR	26	I	Headphone right-channel audio input
HP_INL	27	I	Headphone left-channel audio input
SGND	28	P	Signal ground, connect to CPGND and SPGND
REG_OUT	29	O	Regulated 4.75-V output
VDD	30	P	Positive power supply
GAIN0	31	I	Bit 0, MSB, of gain select bits
GAIN1	32	I	Bit 1, LSB, of gain select bits
Thermal Pad	Die Pad	P	Solder the thermal pad on the bottom of the QFN package to the GND plane of the PCB. It is required for mechanical stability and will enhance thermal performance.

ABSOLUTE MAXIMUM RATINGS

over operating free-air temperature range (unless otherwise noted)(1)

			VALUE	UNIT
	Supply voltage	HPVDD, VDD, SPVDD, CPVDD	-0.3 to 6	V
V_I	Input voltage	SPKR_LIN+, SPKR_LIN-, $\overline{\text{SPKR_RIN}}$+, SPKR_RIN-, HP_EN,GAIN0, GAIN1, $\overline{\text{SPK_EN}}$, REG_EN	-0.3 to 6.3	V
		HP_INL, HP_INR HP Enabled	-3.5 to 3.5	
		HP_INL, HP_INR HP not Enabled	-0.3 to 3.5	
	Continuous total power dissipation		See Dissipation Rating Table	
T_A	Operating free-air temperature range		-40 to 85	°C
T_J	Operating junction temperature range		-40 to 150	°C
T_{stg}	Storage temperature range		-65 to 150	°C
	Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds		260	°C
	Electrostatic discharge	HBM for HP_OUTL and HP_OUTR	8	kV
	Electrostatic discharge, all other pins	CDM	500	V
		HBM	2	kV

(1) Stresses beyond those listed under *absolute maximum ratings* may cause permanent damage to the device. These are stress ratings only, and functional operations of the device at these or any other conditions beyond those indicated under *recommended operating conditions* is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

DISSIPATION RATINGS

PACKAGE(1)	$T_A \leq 25°C$	DERATING FACTOR	$T_A = 70°C$	$T_A = 85°C$
RHB	5.06 W	40 mW/°C	4.04 W	3.23 W

(1) The PowerPAD™ must be soldered to a thermal land on the printed-circuit board. Refer to the Texas Instruments document, PowerPAD™ Thermally Enhanced Package application report (literature number SLMA002) for more information regarding the PowerPAD™ package.

RECOMMENDED OPERATING CONDITIONS

		MIN	MAX	UNIT
Supply voltage	VDD, SPVDD	4.5	5.5	V
Supply voltage	HPVDD, CPVDD	3	5.5	V

RECOMMENDED OPERATING CONDITIONS (continued)

			MIN	MAX	UNIT
V_{IH}	High-level input voltage	$\overline{SPKR_EN}$, HP_EN, GAIN0, GAIN1, REG_EN	2		V
V_{IL}	Low-level input voltage	$\overline{SPKR_EN}$, HP_EN, GAIN0, GAIN1, REG_EN		0.8	V
T_A	Operating free-air temperature		-40	85	°C

GENERAL DC ELECTRICAL CHARACTERISTICS

T_A = 25°C, VDD = SPVDD = HPVDD = CPVDD = 5 V (unless otherwise noted)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
I_{IH}	High-level input current	$\overline{SPKR_EN}$, HP_EN, GAIN0, GAIN1, REG_EN = VDD		0.02	1	µA
I_{IL}	Low-level input current	$\overline{SPKR_EN}$, HP_EN, GAIN0, GAIN1, REG_EN = 0 V		0.02	1	µA
$I_{DD(Speaker)}$	Supply current, speaker amplifier ONLY enabled	$\overline{SPKR_EN}$ = 0 V, HP_EN = REG_EN = 0 V		5	12	mA
$I_{DD(HP)}$	Supply current, headphone amplifier ONLY enabled	$\overline{SPKR_EN}$ = HP_EN = 2 V, REG_EN = 0 V		7.5	14	mA
$I_{DD(REG)}$	Supply current, regulator ONLY enabled	$\overline{SPKR_EN}$ = REG_EN = 2 V, HP_EN = 0 V		0.65	1	mA
$I_{DD(SD)}$	Supply current, shutdown mode	$\overline{SPKR_EN}$ = 2 V, HP_EN = REG_EN = 0 V		2.5	5	µA

SPEAKER AMPLIFIER DC CHARACTERISTICS

T_A = 25°C, VDD = SPVDD = 5 V, R_L = 4 kΩ, Gain = 6 dB (unless otherwise noted)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
$\lvert V_{OO} \rvert$	Output offset voltage (measured differentially)	Inputs AC-coupled to GND, Gain = 6 dB		0.5	10	mV
PSRR	Power supply rejection ratio	VDD = SPVDD = 4.5 V to 5.5 V	-60	-74		dB

SPEAKER AMPLIFIER AC CHARACTERISTICS

T_A = 25°C, VDD = SPVDD = 5 V, R_L = 4 Ω, Gain = 6 dB (unless otherwise noted)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
P_O	Output power	THD+N = 1%, f = 1 kHz, R_L = 8 Ω		1.25		W
		THD+N = 10%, f = 1 kHz, R_L = 8 Ω		1.5		
		THD+N = 1%, f = 1 kHz, R_L = 4 Ω		2		
		THD+N = 10%, f = 1 kHz, R_L = 4 Ω		2.3		
THD+N	Total harmonic distortion plus noise	P_O = 1 W, R_L = 8 Ω, f = 20 Hz to 20 kHz		0.1%		
		P_O = 0.5 W, R_L = 8 Ω, f = 20 Hz to 20 kHz		0.08%		
kSVR	Supply ripple rejection ratio	f = 1 kHz, CBYPASS = 0.47 µF, V_{RIPPLE} = 200 mVp-p		-60		dB
SNR	Signal-to-noise rejection ratio	Maximum output at THD+N <1%, f = 1 kHz, Gain = 6 dB		90		dB
	Crosstalk (Left-Right; Right-Left)	f = 1 kHz, P_o = 1 W, Gain = 6 dB		-80		dB
		f = 10 kHz, P_o = 1 W, Gain = 6 dB		-75		dB
Vn	Noise output voltage	CBYPASS = 0.47 µF, f = 20 Hz to 20 kHz, Gain = 6 dB, No weighting		30		µVrms
Z_I	Input Impedance	Gain = 21.6 dB	15	20		kΩ
G	Gain	GAIN0, GAIN1 = 0.8 V	5.4	6	6.6	dB
		GAIN0 = 0.8 V; GAIN1 = 2 V	9.4	10	10.6	
		GAIN0 = 2 V, GAIN1 = 0.8 V	15	15.6	16.2	
		GAIN0, GAIN1 = 2 V	21	21.6	22.2	
	Gain Matching	Channel-to Channel		0.01		dB
	Start-up time from shutdown	CBYPASS = 0.47 µF		30		ms

HEADPHONE AMPLIFIER DC ELECTRICAL CHARACTERISTICS

T_A = 25°C, HPVDD = CPVDD = VDD = 5 V, R_L = 16 Ω (unless otherwise noted)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
$\lvert V_{OS} \rvert$	Output offset voltage	Inputs grounded		1	3	mV
PSRR	Power supply rejection ratio	HPVDD = 4.5 V to 5.5 V	-75	-100		dB

HEADPHONE AMPLIFIER AC CHARACTERISTICS

T_A = 25°C, HPVDD = 5 V, R_L = 16 Ω (unless otherwise noted)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
P_O	Output power (outputs in phase)	THD+N = 10%, Rl = 16 Ω, f = 1 kHz		200		mW
		THD+N = 10%, Rl = 32 Ω, f = 1 kHz		100		
THD+N	Total harmonic distortion plus noise	P_O = 85 mW, f = 20 Hz to 20 kHz, R_L = 16 Ω		0.03%		
		P_O = 50 mW, f = 20 Hz to20 kHz, R_L = 32 Ω		0.04%		
	Dynamic Range with Signal Present	A-Weighted, f = 20 Hz to 20 kHz		-100		dB FS
kSVR	Supply ripple rejection ratio	f = 1 kHz, 200-mVpp ripple		-60		dB
	Crosstalk	P_o = 35 mW, f = 20 Hz to 20 kHz		-80		dB
SNR	Signal-to-noise ratio	Maximum output at THD+N 1%, f = 1 kHz		95		dB
V_n	Noise output voltage	f = 20 Hz to 20 kHz, No weighting		20		μVrms
Z_I	Input Impedance		15	20		kΩ
Gain	Closed-loop voltage gain	R_L = 16 Ω	-1.45	-1.5	-1.55	V/V
	Start-up time from shutdown			5		ms

LDO CHARACTERISTICS

T_A = 25°C, VDD = 5 V (unless otherwise noted)

PARAMETER		TEST CONDITIONS		MIN	TYP	MAX	UNIT
V_I	Input voltage	V_{DD}		4.5		5.5	V
I_O	Continuous output current			120			mA
V_O	Output voltage	0 < I_O < 120 mA; 4.9 V < Vin < 5.5 V		4.65	4.75	4.85	V
	Dropout voltage	I_O = 120 mA			60	100	mV
	Line regulation	I_L = 5 mA; 4.9 V < Vin < 5.5 V			3	12	mV
	Load regulation	I_L = 0 – 120 mA, Vin = 5 V			0.13	0.23	mV/ mA
	Power supply ripple rejection	V_{DD} = 4.9V, I_L = 10 mA	f = 100 Hz		46		dB

TYPICAL CHARACTERISTICS

Default graph conditions: Vcc = 5 V, Freq = 1 kHz, AES17 Filter.

TOTAL HARMONIC DISTORTION + NOISE (SP)
vs
FREQUENCY

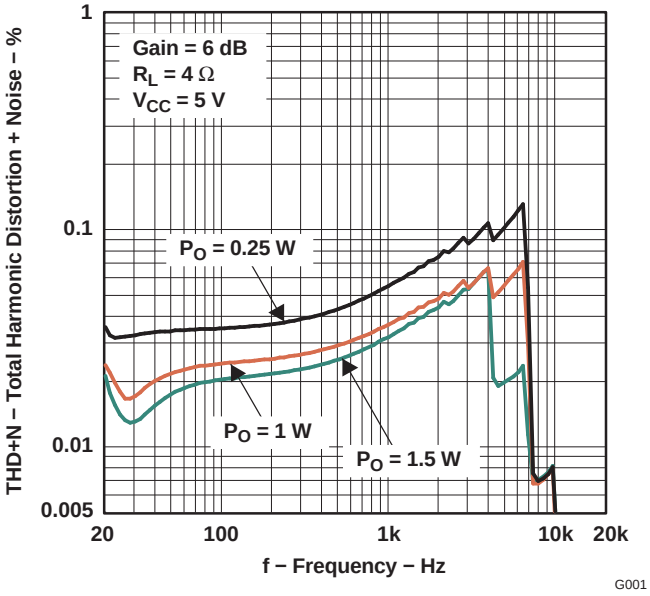


Figure 1.

TOTAL HARMONIC DISTORTION + NOISE (SP)
vs
FREQUENCY

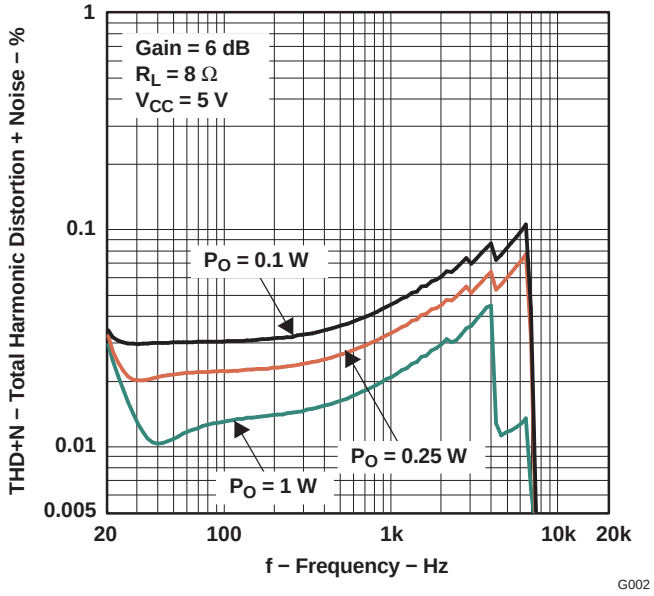


Figure 2.

TOTAL HARMONIC DISTORTION + NOISE (HP)
vs
FREQUENCY

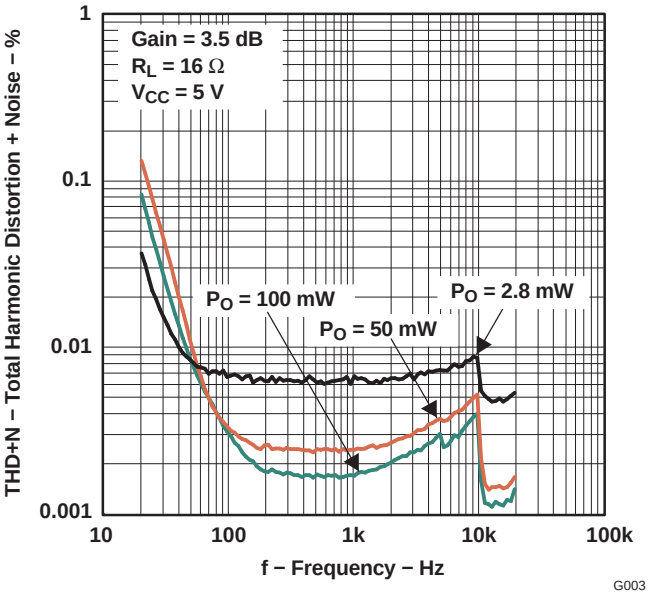


Figure 3.

TOTAL HARMONIC DISTORTION + NOISE (HP)
vs
FREQUENCY

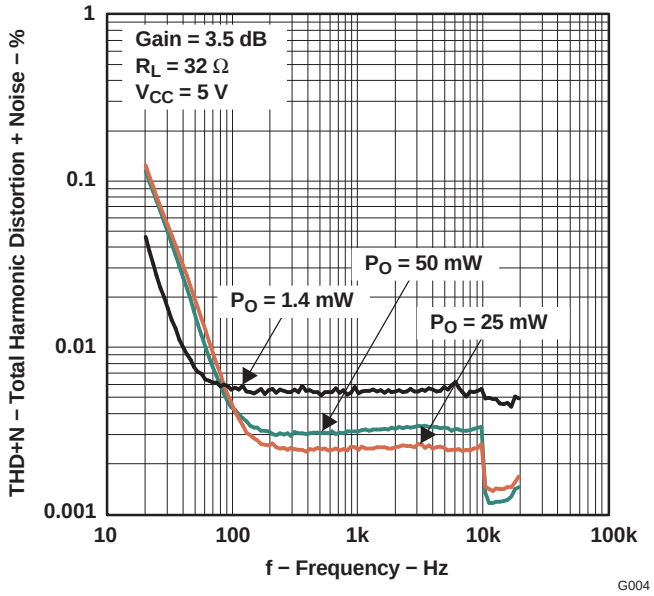


Figure 4.

TYPICAL CHARACTERISTICS (continued)

TOTAL HARMONIC DISTORTION + NOISE (SP)
vs
OUTPUT POWER

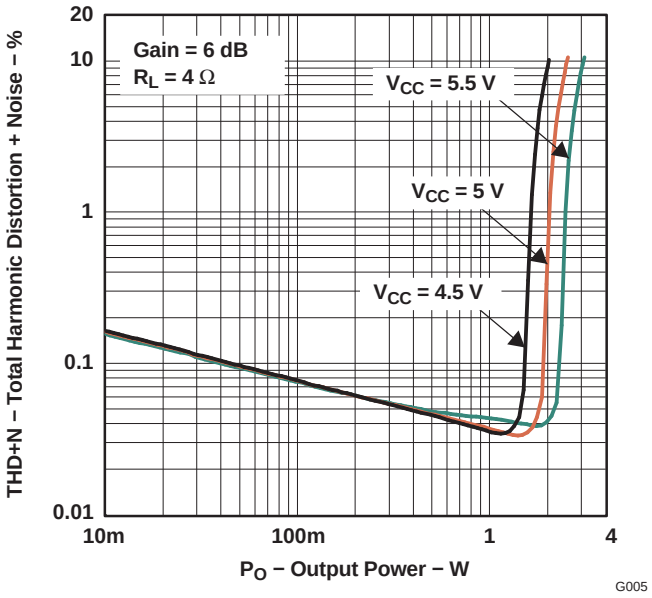


Figure 5.

TOTAL HARMONIC DISTORTION + NOISE (SP)
vs
OUTPUT POWER

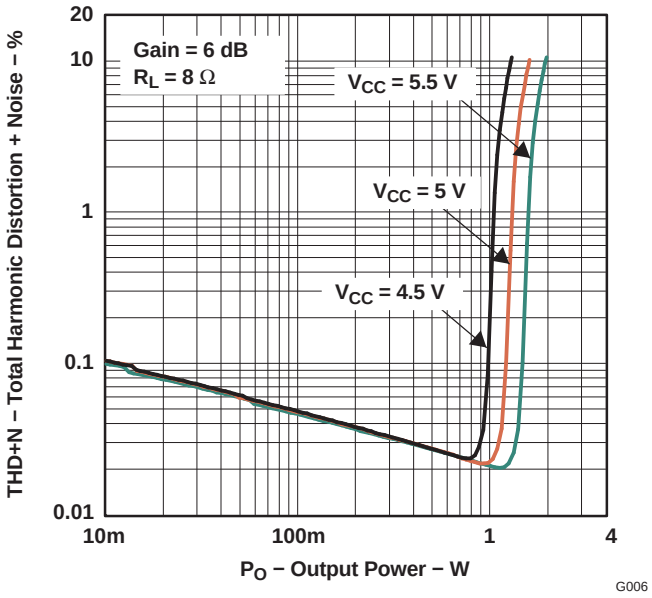


Figure 6.

TOTAL HARMONIC DISTORTION + NOISE (HP)
vs
OUTPUT POWER

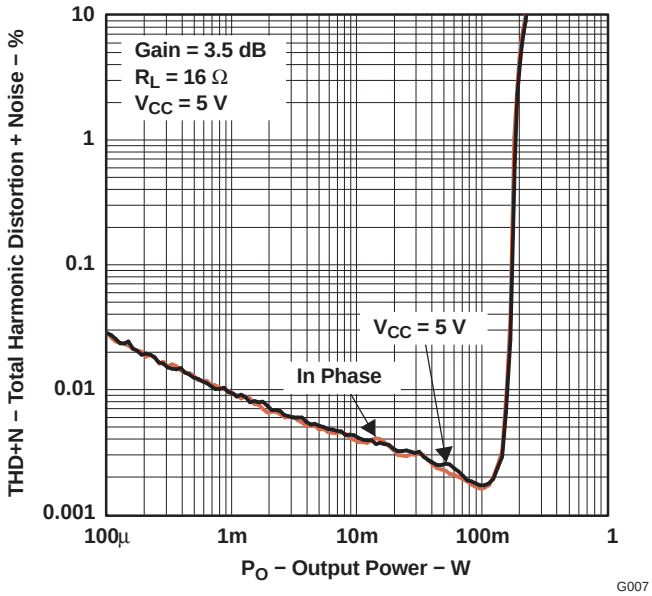


Figure 7.

TOTAL HARMONIC DISTORTION + NOISE (HP)
vs
OUTPUT POWER

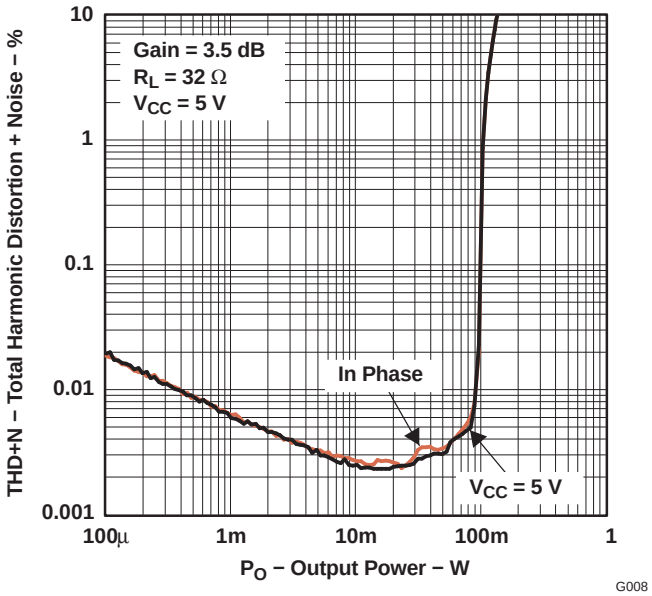


Figure 8.

TYPICAL CHARACTERISTICS (continued)

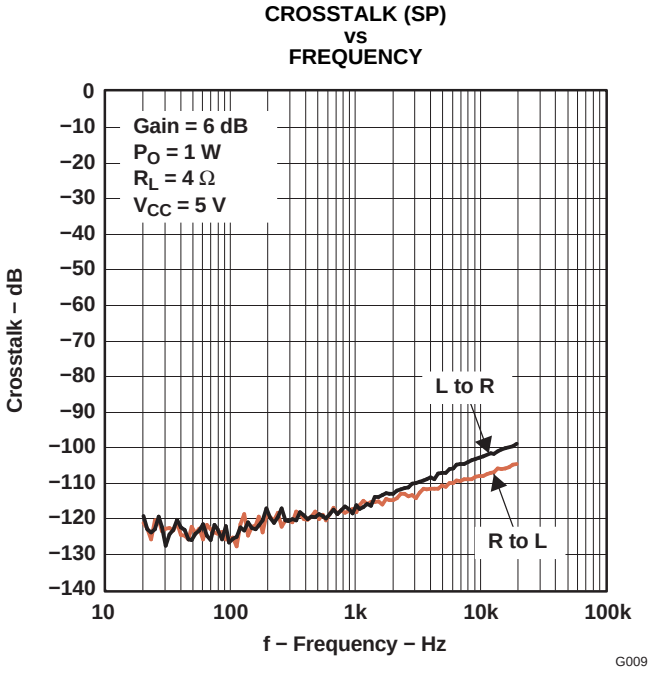


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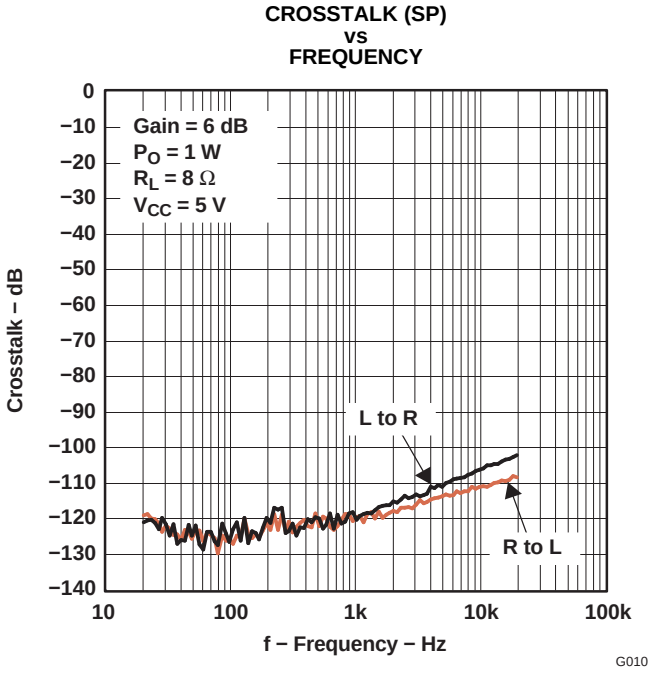


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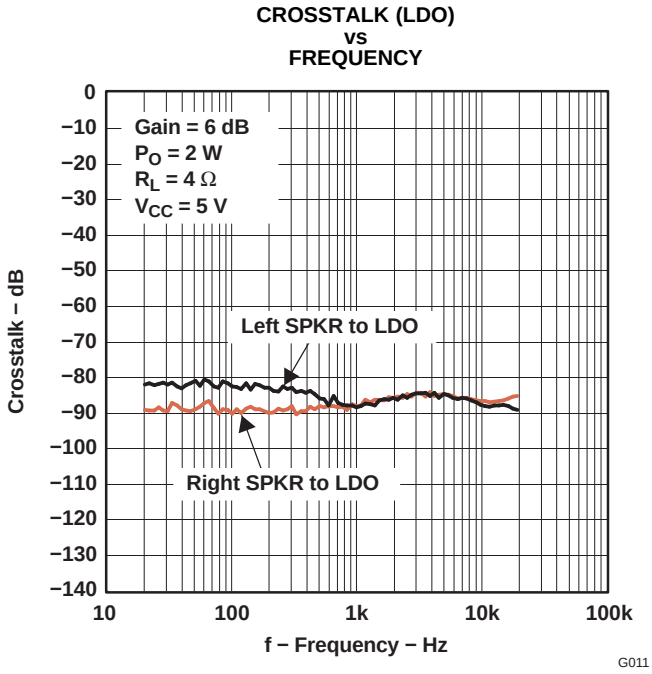


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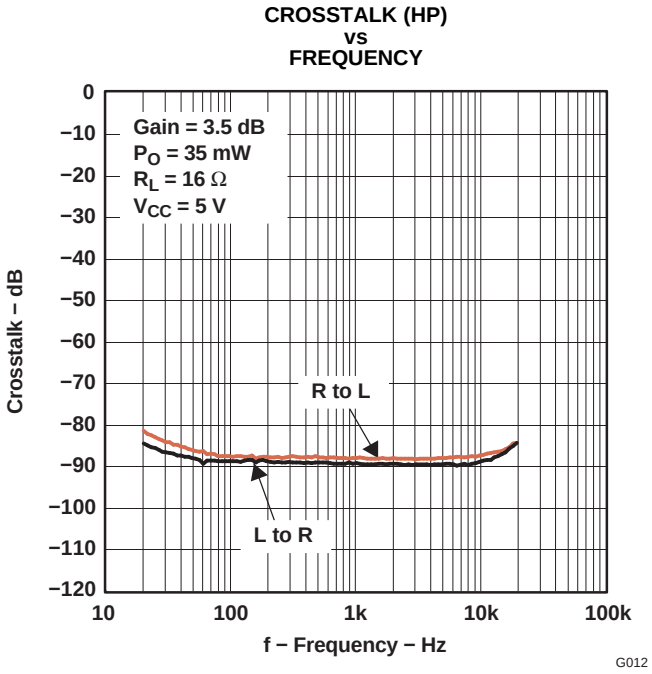


Figure 12.

TYPICAL CHARACTERISTICS (continued)

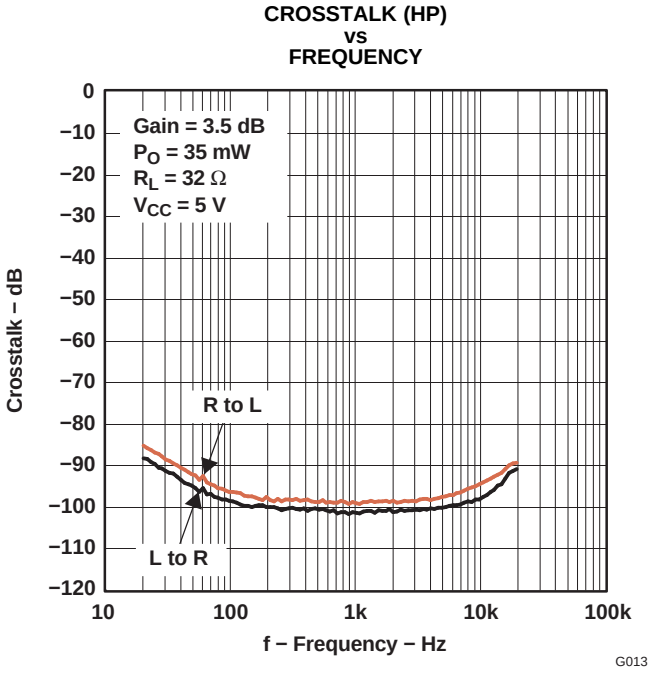


Figure 13.

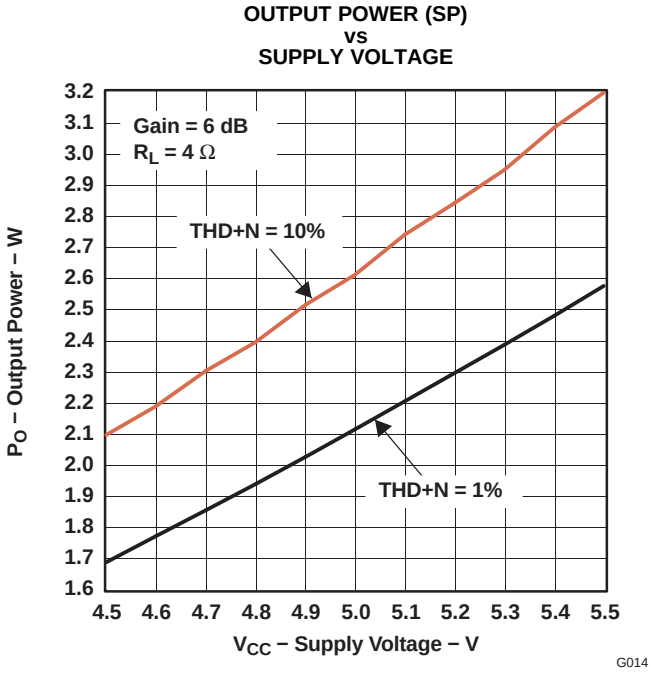


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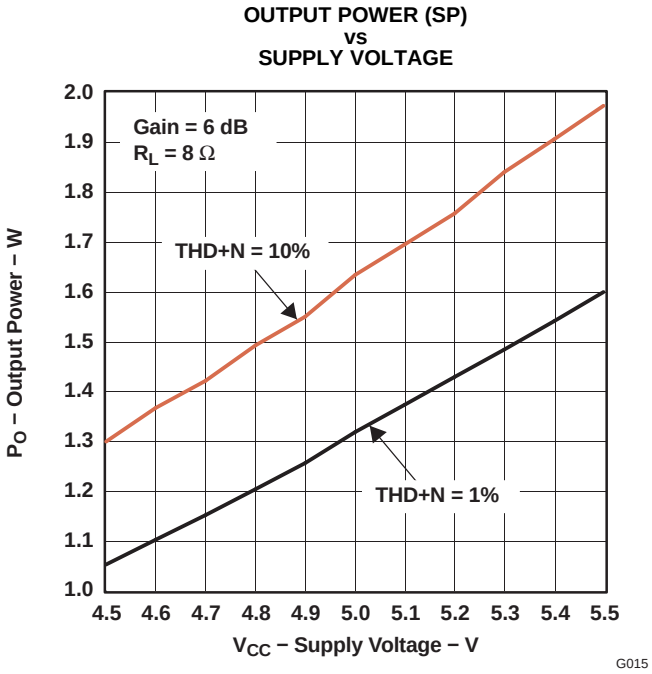


Figure 15.

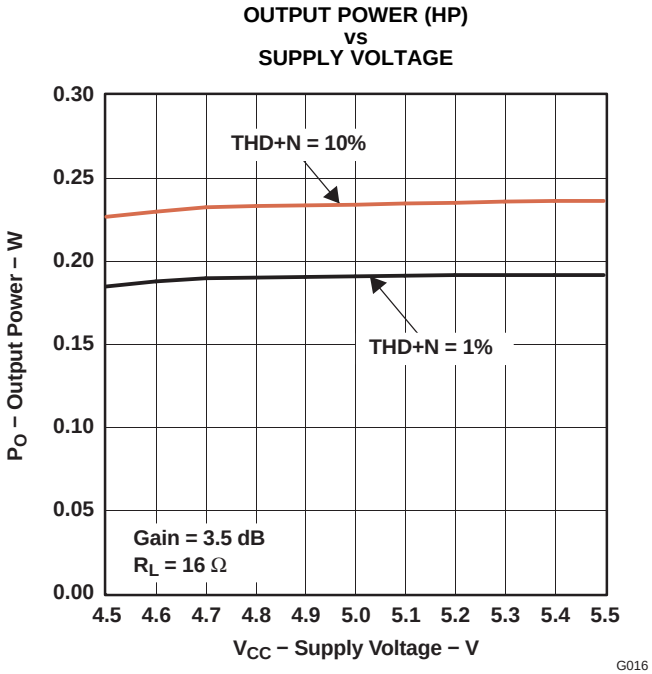


Figure 16.

TYPICAL CHARACTERISTICS (continued)

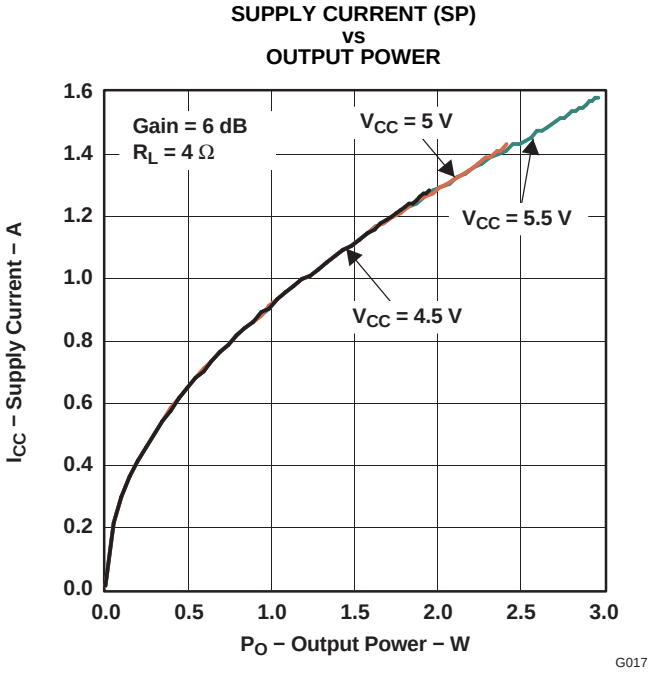


Figure 17.

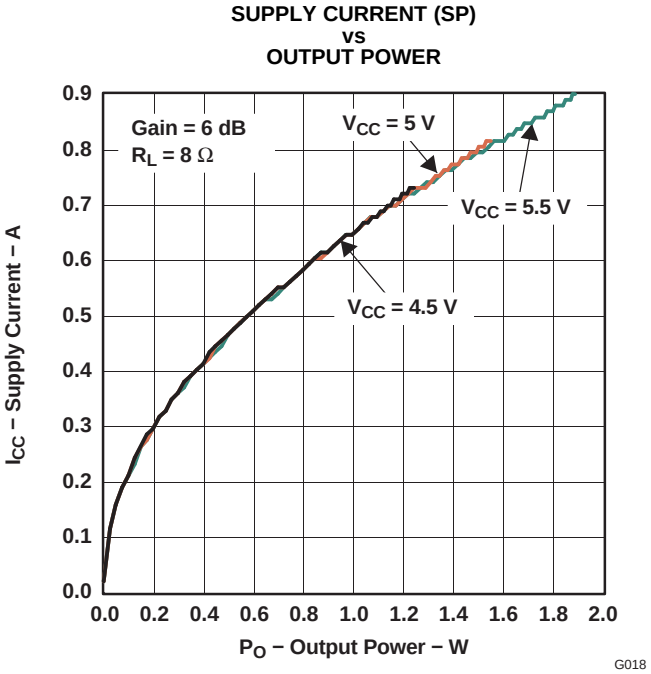


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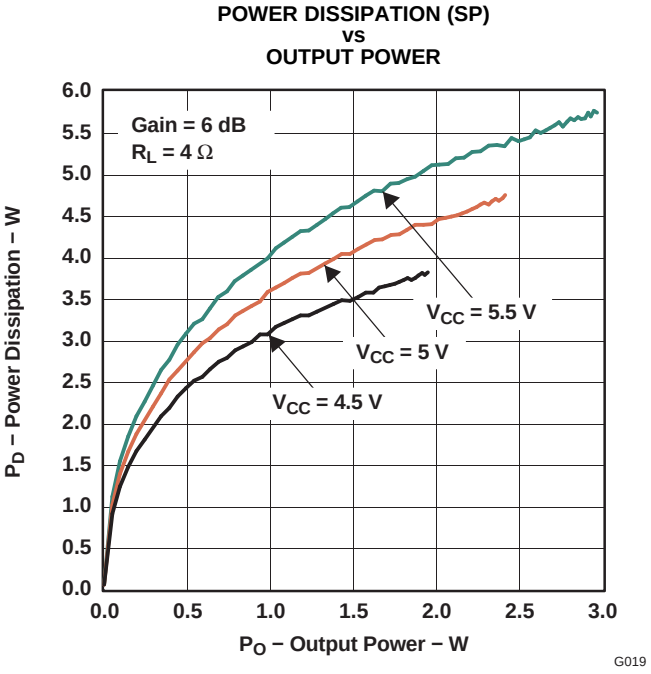


Figure 19.

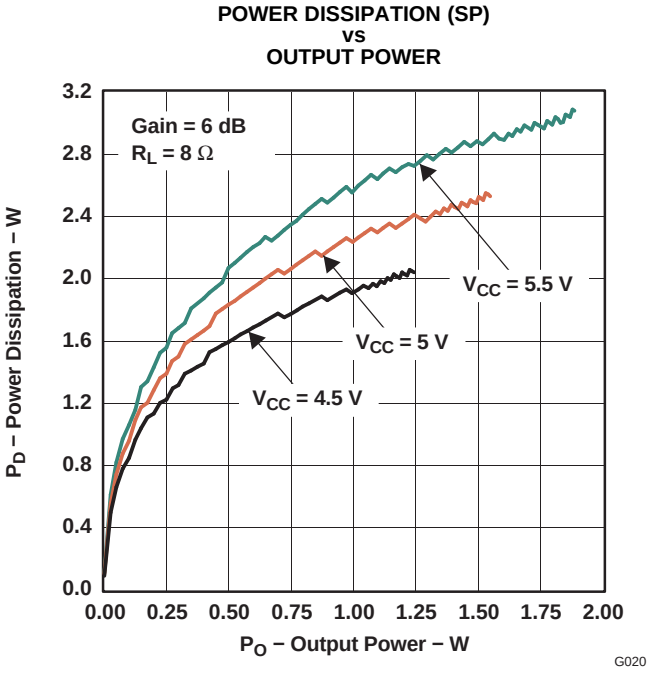


Figure 20.

TYPICAL CHARACTERISTICS (continued)

REGULATOR OUTPUT VOLTAGE (LDO)
vs
SUPPLY VOLTAGE

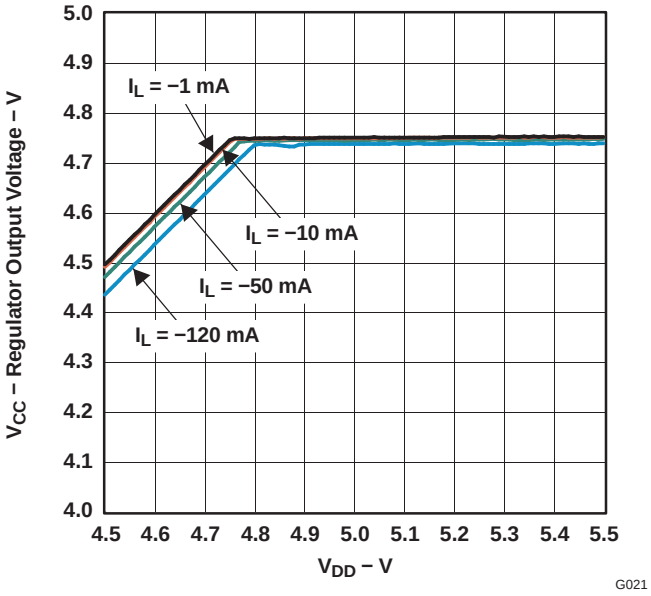


Figure 21.

SUPPLY VOLTAGE (LDO)
vs
LOAD CURRENT

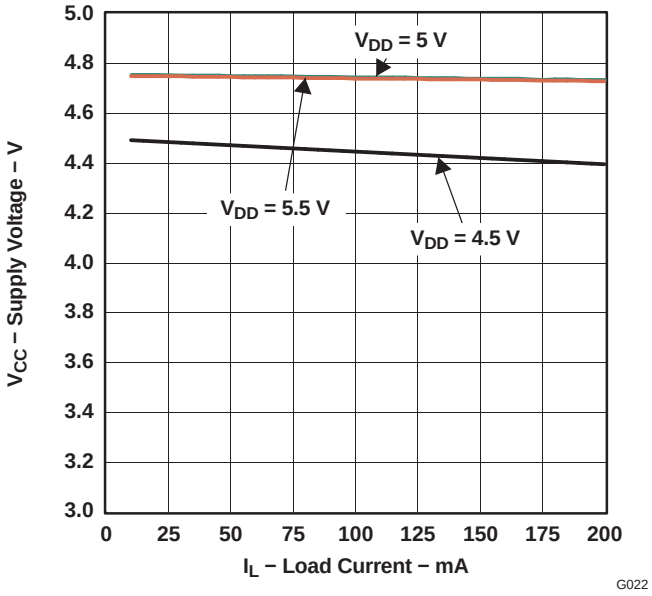


Figure 22.

DROPOUT VOLTAGE (LDO)
vs
LOAD CURRENT

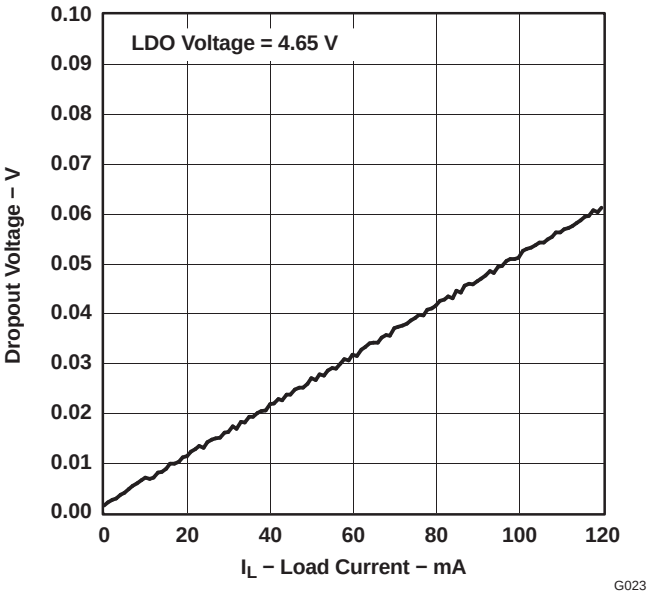


Figure 23.

COMMON-MODE REJECTION RATIO (SP)
vs
FREQUENCY

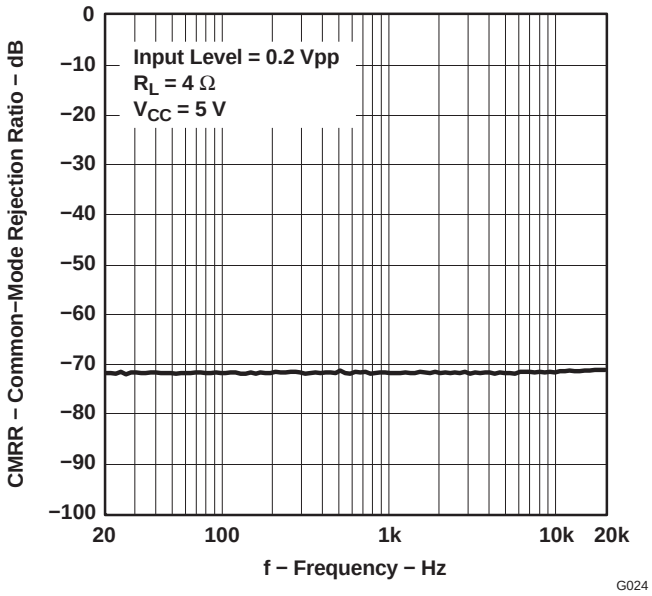


Figure 24.

TYPICAL CHARACTERISTICS (continued)

**COMMON-MODE REJECTION RATIO (SP)
vs
FREQUENCY**

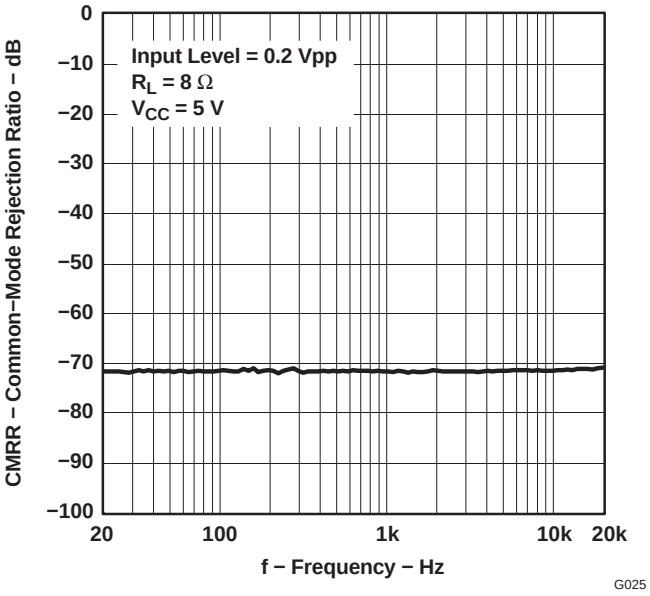


Figure 25.

**POWER SUPPLY REJECTION RATIO (LDO)
vs
FREQUENCY**

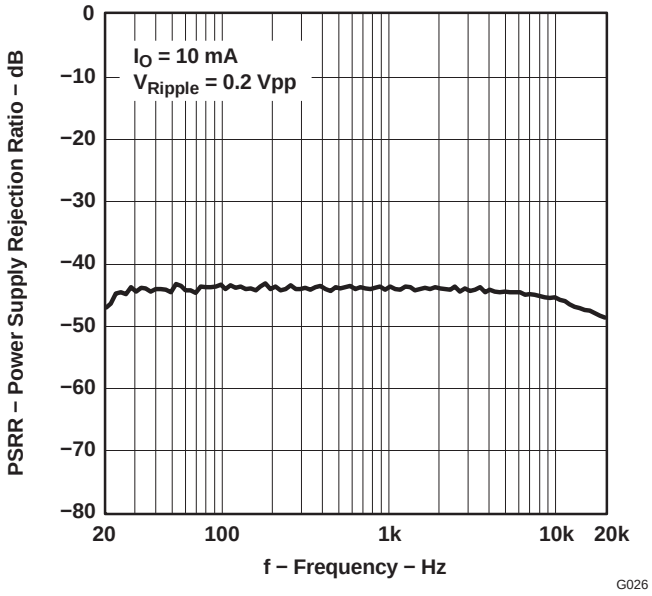


Figure 26.

**POWER SUPPLY REJECTION RATIO (SP)
vs
FREQUENCY**

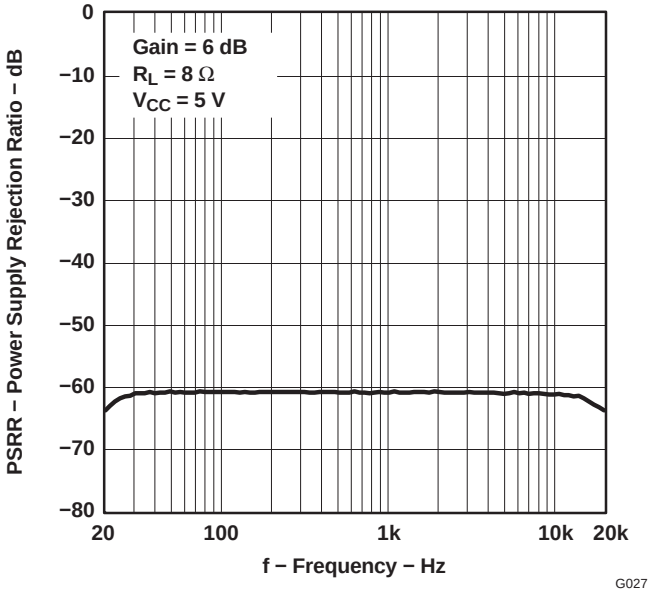


Figure 27.

**POWER SUPPLY REJECTION RATIO (SP)
vs
FREQUENCY**

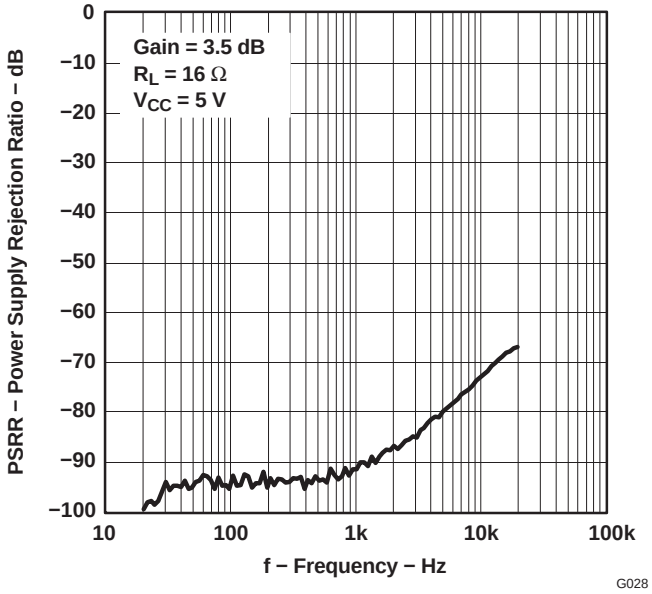


Figure 28.

TYPICAL CHARACTERISTICS (continued)

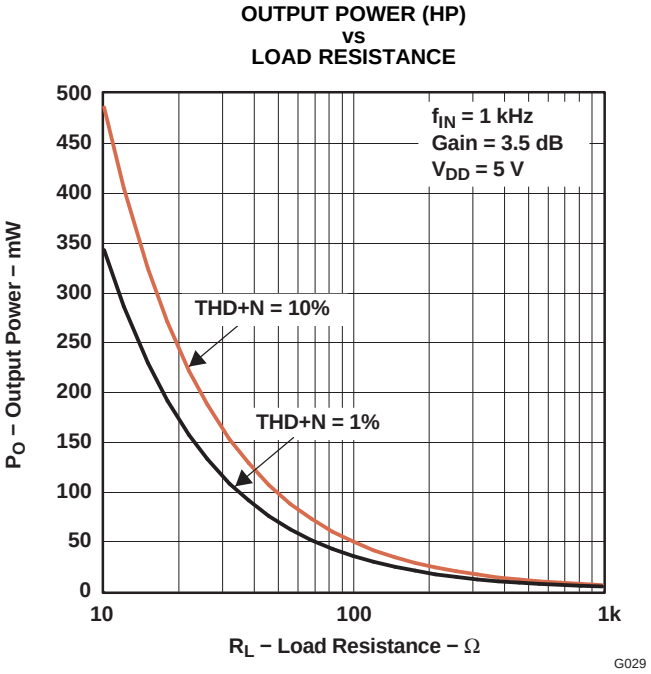


Figure 29.

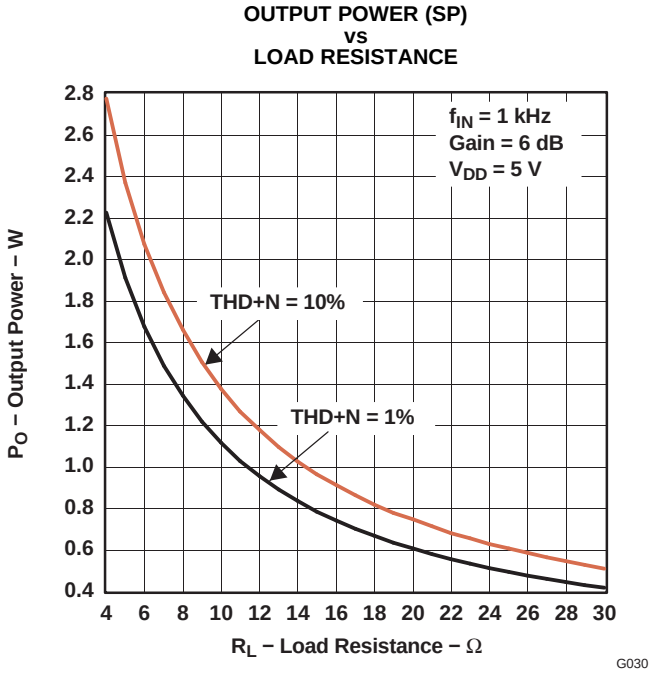


Figure 30.

APPLICATION INFORMATION

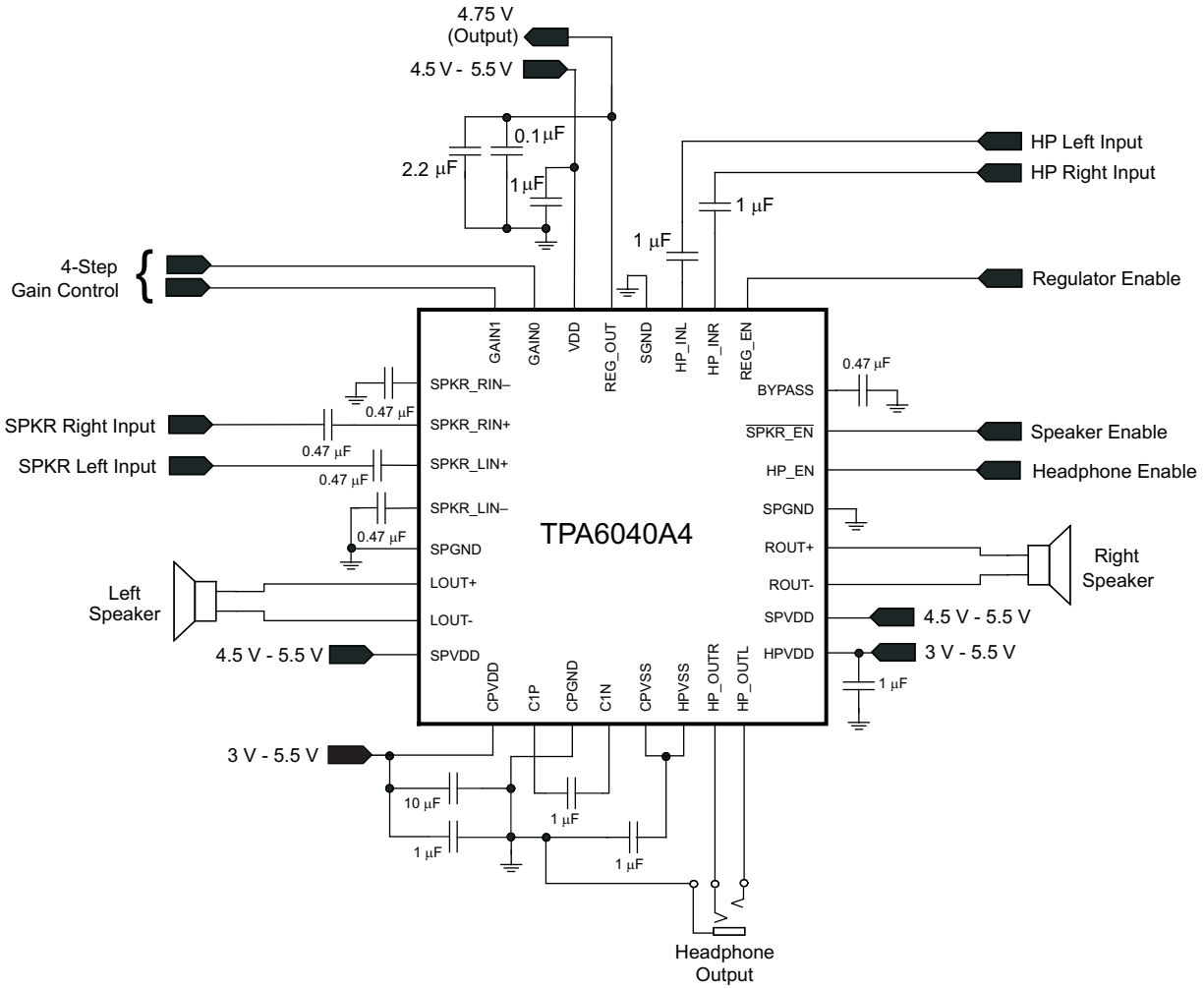


Figure 31. Single-Ended Input Application Circuit

APPLICATION INFORMATION (continued)

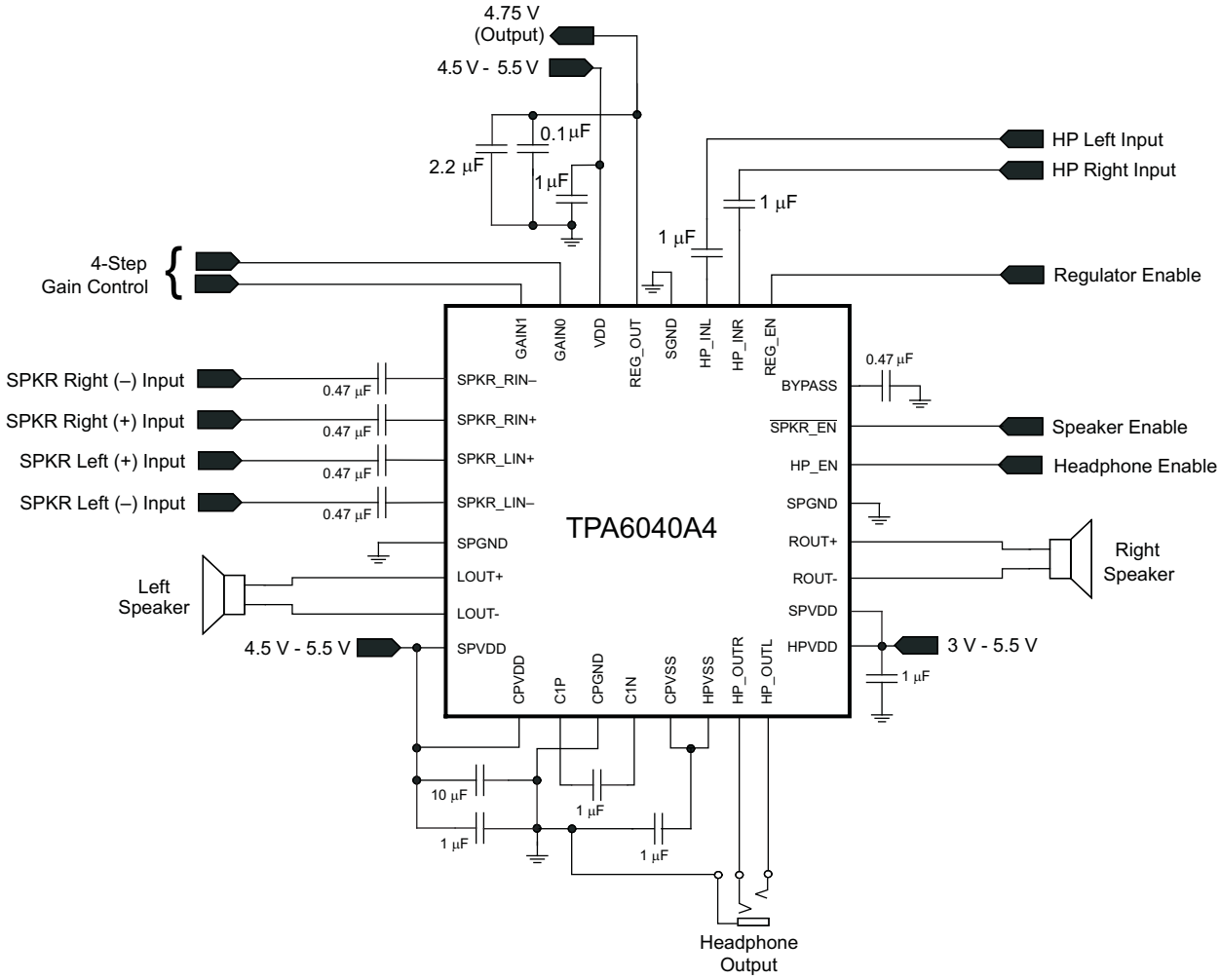


Figure 32. Differential Input Application Circuit

Power Enable Modes

The TPA6040A4 allows disable of any or all of the main circuit blocks when not in use in order to reduce operating power to an absolute minimum. The $\overline{\text{SPKR_EN}}$ control can be used to disable the speaker amplifier while the HP_EN can be used separately to turn off the headphone amplifier. The LDO also has an independent power control, REG_EN. With all circuit blocks disabled, the supply current in shutdown mode is only 5 µA. See the General DC Electrical Characteristics for operating currents with each circuit block operating independently.

Speaker Amplifier Description

The speaker amplifier is capable of driving 2 W/ch of continuous RMS power into a 4-Ω load at 5 V. An internal 4-step control allows variation of the gain from 6 dB to 21.6 dB.

Fully Differential Amplifier

The TPA6040A4 speaker amplifier is a fully differential amplifier with differential inputs and outputs. The fully differential architecture consist of a differential amplifier and a common mode amplifier. The differential amplifier ensures that the amplifier outputs a differential voltage that is equal to the differential input times the gain. The common-mode voltage at the output is biased around $V_{DD}/2$ regardless of the common-mode voltage at the input.

APPLICATION INFORMATION (continued)

One of the primary advantages of the fully differential amplifier is improved RF immunity. GSM handsets save power by turning on and off the RF transmitter at a rate of 217 Hz. The transmitted signal is picked up on input and output traces. The fully differential amplifier cancels the signal and others of this type much better than typical audio amplifiers.

Gain Setting via GAIN0 and GAIN1 Inputs

The gain of the TPA6040A4 is set by two terminals, GAIN0 and GAIN1. The gains listed in Table 1 are realized by changing the taps on the input resistors and feedback resistors inside the amplifier. This causes the input impedance (Z_I) to vary as a function of the gain setting.

Gain Setting

GAIN1	GAIN0	AMPLIFIER GAIN (dB)	INPUT IMPEDANCE (kΩ)
		TYPICAL	TYPICAL
0	0	6	108
0	1	10	78
1	0	15.6	46
1	1	21.6	25

Input Capacitor, C_I

The input capacitor allows the amplifier to bias the input signal to the proper dc level for proper operation. In this case, the input capacitor, C_I, and the input impedance of the amplifier, R_I, form a high-pass filter with the corner frequency determined in Equation 1. Figure 33 shows how the input capacitor and the input resistor within the amplifier interact.

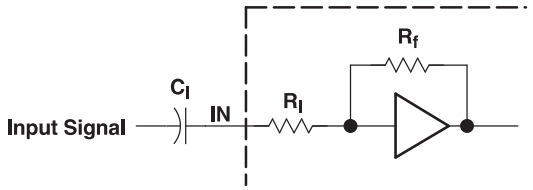
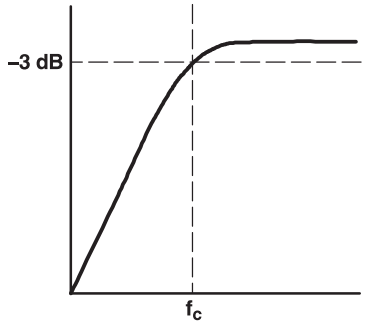


Figure 33. Input Resistor and Input Capacitor

$$f_{c(highpass)} = \frac{1}{2\pi R_I C_I} \quad (1)$$



(1)

The value of C_I is important to consider as it directly affects the low-frequency, or bass, performance of the circuit. Furthermore, the input impedance changes with a change in volume. The higher the volume, the lower the input impedance is. To determine the appropriate capacitor value, reconfigure Equation 1 into Equation 2. The value of the input resistor, R_I, can be determined from Equation 2.

$$C_I = \frac{1}{2\pi R_I f_c} \quad (2)$$

Low-leakage tantalum or ceramic capacitors are recommended. When polarized capacitors are used, the positive side of the capacitor should face the amplifier input in most applications as the dc level there is held at VCC/2, which is likely higher than the source dc level. Note that it is important to confirm the capacitor polarity in each specific application. Recommended capacitor values are between 0.1 µF and 1 µF.

Windows Vista™ Premium Mode Specifications

Device Type	Requirement	Windows Premium Mobile Vista Specifications	TPA6040A4 Typical Performance
Analog Speaker Output Jack (R_L = 8Ω, FS = 0.707 Vrms)	THD+N	≤ -65 dB FS [20 Hz, 20 kHz]	-74 dB FS[20 Hz, 20 kHz]
	Dynamic Range with Signal Present	≤ -80 dB FS A-Weight	-89 dB FS A-Weight
	Line Output Crosstalk	≤ -60 dB [20 Hz, 20 kHz]	-100 dB [20 Hz, 20 kHz]
Analog Headphone Out Jack (R_L = 32Ω, FS = 0.300Vrms)	THD+N	≤ -45 dB FS [20 Hz, 20 kHz]	-81 dB FS [20 Hz, 20 kHz]
	Dynamic Range with Signal Present	≤ -80 dB FS A-Weight	-100 dB FS A-Weight
	Headphone Output Crosstalk	≤ -60 dB [20 Hz, 20 kHz]	-82 dB [20 Hz, 20 kHz]

Bridge-Tied Load Versus Single-Ended Mode

Figure 34 shows a Class-AB audio power amplifier (APA) in a bridge-tied-load (BTL) configuration. The TPA6040A4 speaker amplifier consists of two Class-AB differential amplifiers per channel driving the positive and negative terminals of the load. Specifically, differential drive means that as one side of the amplifier (the positive terminal, for example) is slewing up, the other side is slewing down, and vice versa. This doubles the voltage swing across the load as opposed to a ground-referenced load, or a single-ended load. Power is proportional to the square of the voltage. Plugging 2x VO(PP) into the power equation yields 4X the output power from the same supply rail and load impedance as would have been obtained with a ground-referenced load (see Equation 3).

$$V_{(RMS)} = \frac{V_{O(PP)}}{2\sqrt{2}}$$

$$\text{Power} = \frac{V_{(RMS)}{}^2}{R_L} \quad (3)$$

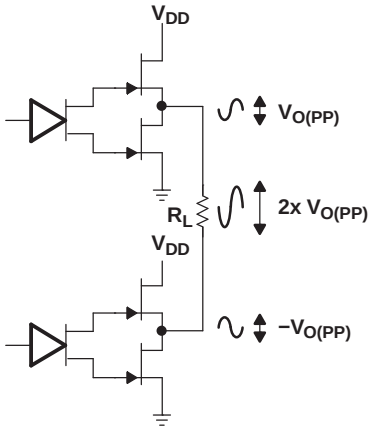


Figure 34. Differential Output Configuration

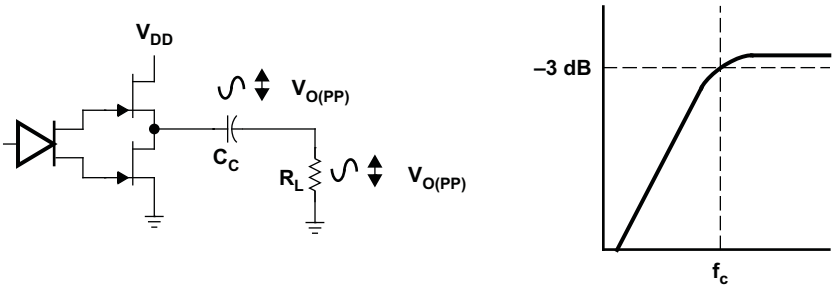


Figure 35. Single-Ended Configuration and Frequency Response

Bridge-tying the outputs in a typical computer audio, LCD TV, or multimedia LCD monitor application drastically increases output power. For example, if an amplifier in a single-ended configuration was capable of outputting a maximum of 250 mW for a given load with a supply voltage of 12 V, then that same amplifier would be able to output 1 W of power in a BTL configuration with the same supply voltage and load. In addition to the increase in output power, the BTL configuration does not suffer from the same low-frequency issues that plague the single-ended configuration. In a BTL configuration, there is no need for an output capacitor to block dc, so no unwanted filtering occurs. In addition, the BTL configuration saves money and space, as the dc-blocking capacitors needed for single-ended operation are large and expensive. For example, with an 8-Ω load in SE operation, the user needs a 1000-µF capacitor to obtain a cutoff frequency below 20 Hz. This capacitor is expensive and large.

Headphone Amplifier Description

The headphone amplifier has a fixed gain of -1.5 V/V. It uses single-ended (SE) inputs. The DirectPath™ amplifier architecture operates from a single supply but makes use of an internal charge pump to provide a negative voltage rail. Combining the user-provided positive rail and the negative rail generated by the IC, the device operates in what is effectively a split supply mode. The output voltages are now centered at zero volts with the capability to swing to the positive rail or negative rail. The DirectPath™ amplifier requires no output dc blocking capacitors and does not place any voltage on the sleeve. The block diagram and waveform of Figure 36 illustrate the ground-referenced headphone architecture. This is the architecture of the TPA6040A4.

Single-supply headphone amplifiers typically require dc-blocking capacitors. The capacitors are required because most headphone amplifiers have a dc bias on the outputs pin. If the dc bias is not removed, the output signal is severely clipped, and large amounts of dc current rush through the headphones, potentially damaging them. The left-side drawing in Figure 36 illustrates the conventional headphone amplifier connection to the headphone jack and output signal.

DC blocking capacitors are often large in value. The headphone speakers (typical resistive values of 16 Ω or 32 Ω) combine with the dc blocking capacitors to form a high-pass filter. Equation 4 shows the relationship between the load impedance (R_L), the capacitor (C_O), and the cutoff frequency (f_C).

$$f_c = \frac{1}{2\pi R_L C_O} \tag{4}$$

C_O can be determined using Equation 5, where the load impedance and the cutoff frequency are known.

$$C_O = \frac{1}{2\pi R_L f_c} \tag{5}$$

If f_c is low, the capacitor must then have a large value because the load resistance is small. Large capacitance values require large package sizes. Large package sizes consume PCB area, stand high above the PCB, increase cost of assembly, and can reduce the fidelity of the audio output signal.

Two different headphone amplifier applications are available that allow for the removal of the output dc blocking capacitors. The capacitor-less amplifier architecture is implemented in the same manner as the conventional amplifier with the exception of the headphone jack shield pin. This amplifier provides a reference voltage, which

is connected to the headphone jack shield pin. This is the voltage on which the audio output signals are centered. This voltage reference is half of the amplifier power supply to allow symmetrical swing of the output voltages. Do not connect the shield to any GND reference, or large currents will result. The scenario can happen if, for example, an accessory other than a floating GND headphone is plugged into the headphone connector. See the second block diagram and waveform in Figure 36.

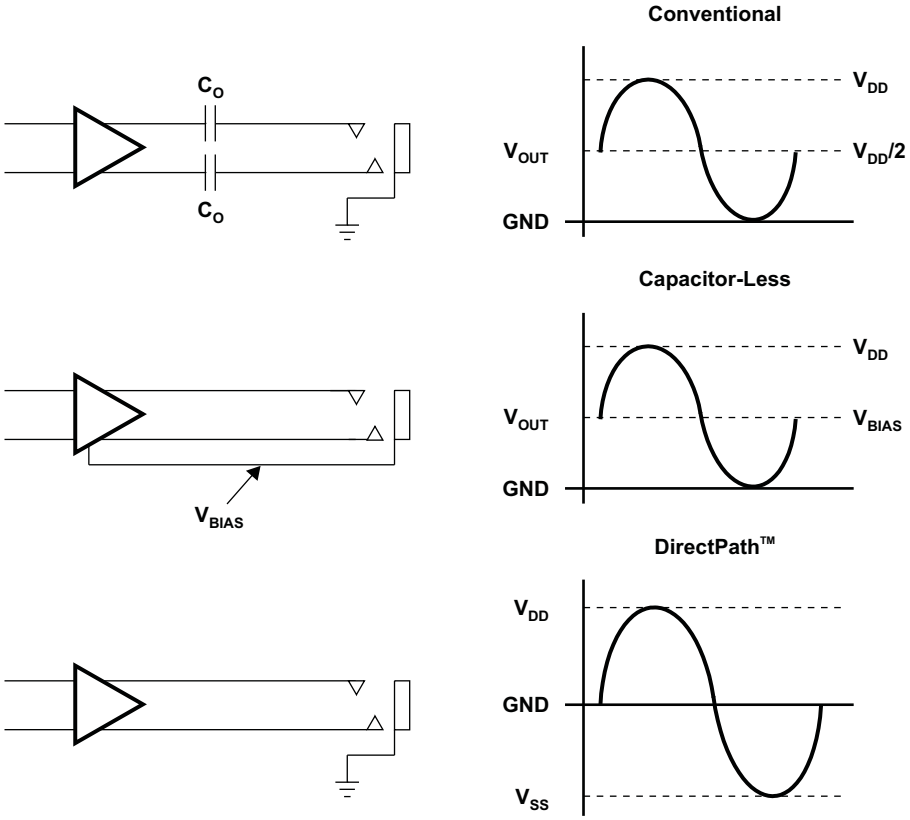


Figure 36. Amplifier Applications

Input-Blocking Capacitors

DC input-blocking capacitors block the dc portion of the audio source and allow the inputs to properly bias. Maximum performance is achieved when the inputs of the TPA6040A4 are properly biased. Performance issues such as pop are optimized with proper input capacitors.

The dc input-blocking capacitors can be removed, provided the inputs are connected differentially and within the input common-mode range of the amplifier, the audio signal does not exceed ±3 V, and pop performance is sufficient.

C_{IN} is a theoretical capacitor used for mathematical calculations only. Its value is the series combination of the dc input-blocking capacitors, $C_{(DCINPUT-BLOCKING)}$. Use Equation 6 to determine the value of $C_{(DCINPUT-BLOCKING)}$. For example, if C_{IN} is equal to 0.22 µF, then $C_{(DCINPUT-BLOCKING)}$ is equal to about 0.47 µF.

$$C_{IN} = \frac{1}{2} C_{(DCINPUT-BLOCKING)} \quad (6)$$

The two $C_{(DCINPUT-BLOCKING)}$ capacitors form a high-pass filter with the input impedance of the TPA6040A4. Use Equation 6 to calculate C_{IN}, then calculate the cutoff frequency using C_{IN} and the differential input impedance of the TPA6040A4, R_{IN}, using Equation 7. Note that the differential input impedance changes with gain. See Figure 32 for input impedance values. The frequency and/or capacitance can be determined when one of the two values are given.

$$fc_{IN} = \frac{1}{2\pi R_{IN} C_{IN}} \quad \text{or} \quad C_{IN} = \frac{1}{2\pi fc_{IN} R_{IN}} \quad (7)$$

If a high-pass filter with a -3-dB point of no more than 20 Hz is desired over all gain settings, the minimum impedance would be used in the Equation 7. The minimum input impedance for TPA6040A4 is 20 kΩ. The capacitor value by Equation 7 would be 0.399 µF. However, this is C_{IN}, and the desired value is for $C_{(DCINPUT-BLOCKING)}$. Multiplying C_{IN} by 2 yields 0.80 µF, which is close to the standard capacitor value of 1 µF. Place 1-µF capacitors at each input terminal of the TPA6040A4 to complete the filter.

Charge Pump Flying Capacitor and CPVSS Capacitor

The charge pump flying capacitor serves to transfer charge during the generation of the negative supply voltage. The CPVSS capacitor must be at least equal to the flying capacitor in order to allow maximum charge transfer. Low ESR capacitors are an ideal selection, and a value of 1 µF is typical.

Decoupling Capacitors

The TPA6040A4 is a DirectPath™ headphone amplifier that requires adequate power supply decoupling to ensure that the noise and total harmonic distortion (THD) are as low as possible. To filter high-frequency transients, spikes, and digital hash on the power line, use good low equivalent-series-resistance (ESR) ceramic capacitors, typically 1 µF. Find the smallest package possible, and place as close as possible to the device V_{DD} lead. Placing the decoupling capacitors close to the TPA6040A4 is important for the performance of the amplifier. Use a 10 µF or greater capacitor near the TPA6040A4 to filter lower frequency noise signals; however, the high PSRR of the TPA6040A4 makes the 10-µF capacitor unnecessary in most applications.

Midrail Bypass Capacitor, C_{BYPASS}

The midrail bypass capacitor, $C_{(BYPASS)}$, has several important functions. During start-up or recovery from shutdown mode, C_{BYPASS} determines the rate at which the amplifier starts up. A 1-µF capacitor yields a start-up time of approximately 30 ms. C_{BYPASS} also reduces the noise coupled into the output signal by the power supply. This improves the power supply ripple rejection (PSRR) of the amplifier. Ceramic or polyester capacitors with low ESR and values in the range of 0.47 µF to 1 µF are recommended.

LOW DROPOUT REGULATOR (LDO) DESCRIPTION

The TPA6040A4 contains a 4.75-V output low dropout regulator (LDO) capable of providing a maximum of 120 mA with a drop of less than 150 mV from the 5-V supply. This can be used to power an external CODEC. A 10-µF decoupling capacitor is recommended at the output of the LDO as well as 0.1-µF capacitor to filter high-frequency noise from the supply line.

LAYOUT RECOMMENDATIONS

Solder the exposed thermal pad (metal pad on the bottom of the part) on the TPA6040A4 QFN package to a pad on the PCB.

It is important to keep the TPA6040A4 external components close to the body of the amplifier to limit noise pickup. One should lay out the differential input leads symmetrical and close together to take advantage of the inherent common mode rejection of the TPA6040A4. The layout of the TPA6040A4 evaluation module (EVM) is a good example of component placement and the layout files are available at ti.com.

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
TPA6040A4RHBR	ACTIVE	VQFN	RHB	32	3000	Green (RoHS & no Sb/Br)	NIPDAU	Level-3-260C-168 HR	-40 to 85	TPA 6040A4	Samples
TPA6040A4RHBRG4	ACTIVE	VQFN	RHB	32	3000	Green (RoHS & no Sb/Br)	NIPDAU	Level-3-260C-168 HR	-40 to 85	TPA 6040A4	Samples

(1) The marketing status values are defined as follows:
ACTIVE: Product device recommended for new designs.
LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.
NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.
PREVIEW: Device has been announced but is not in production. Samples may or may not be available.
OBSOLETE: TI has discontinued the production of the device.

(2) **RoHS:** TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".
RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.
Green: TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

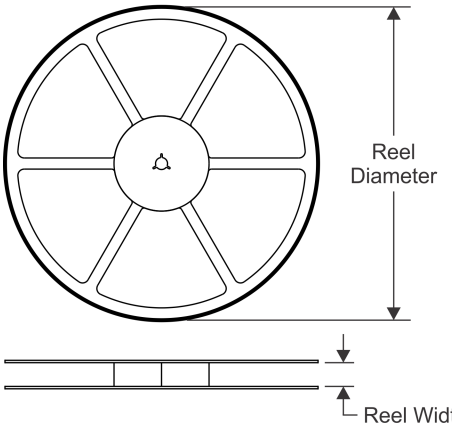
(6) Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

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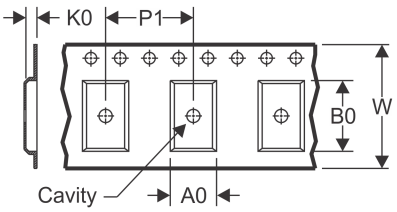
In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

TAPE AND REEL INFORMATION

REEL DIMENSIONS

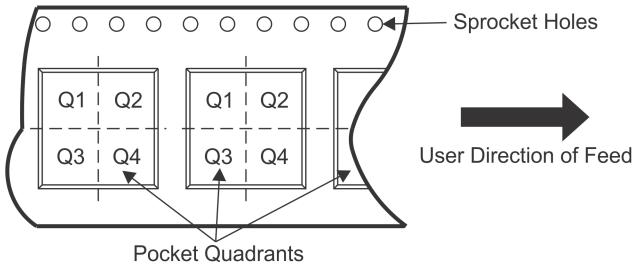


TAPE DIMENSIONS



A0	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

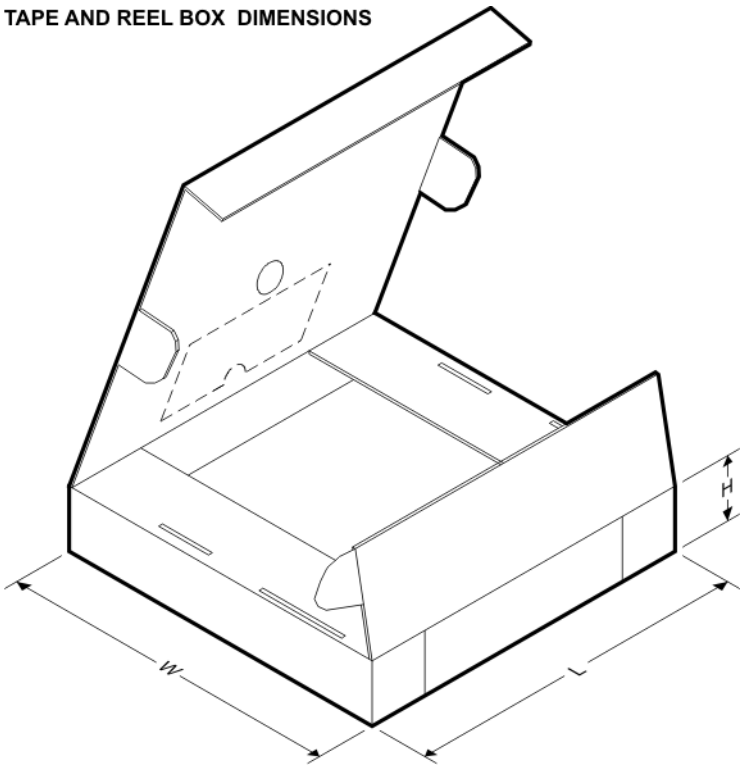
QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TPA6040A4RHBR	VQFN	RHB	32	3000	330.0	12.4	5.3	5.3	1.1	8.0	12.0	Q2

TAPE AND REEL BOX DIMENSIONS



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TPA6040A4RHBR	VQFN	RHB	32	3000	367.0	367.0	35.0

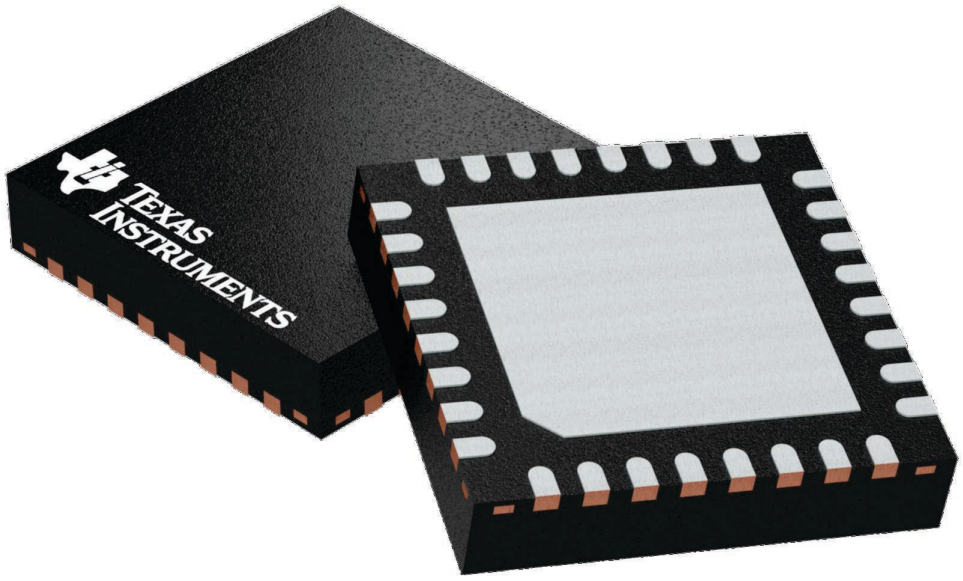
GENERIC PACKAGE VIEW

RHB 32

VQFN - 1 mm max height

5 x 5, 0.5 mm pitch

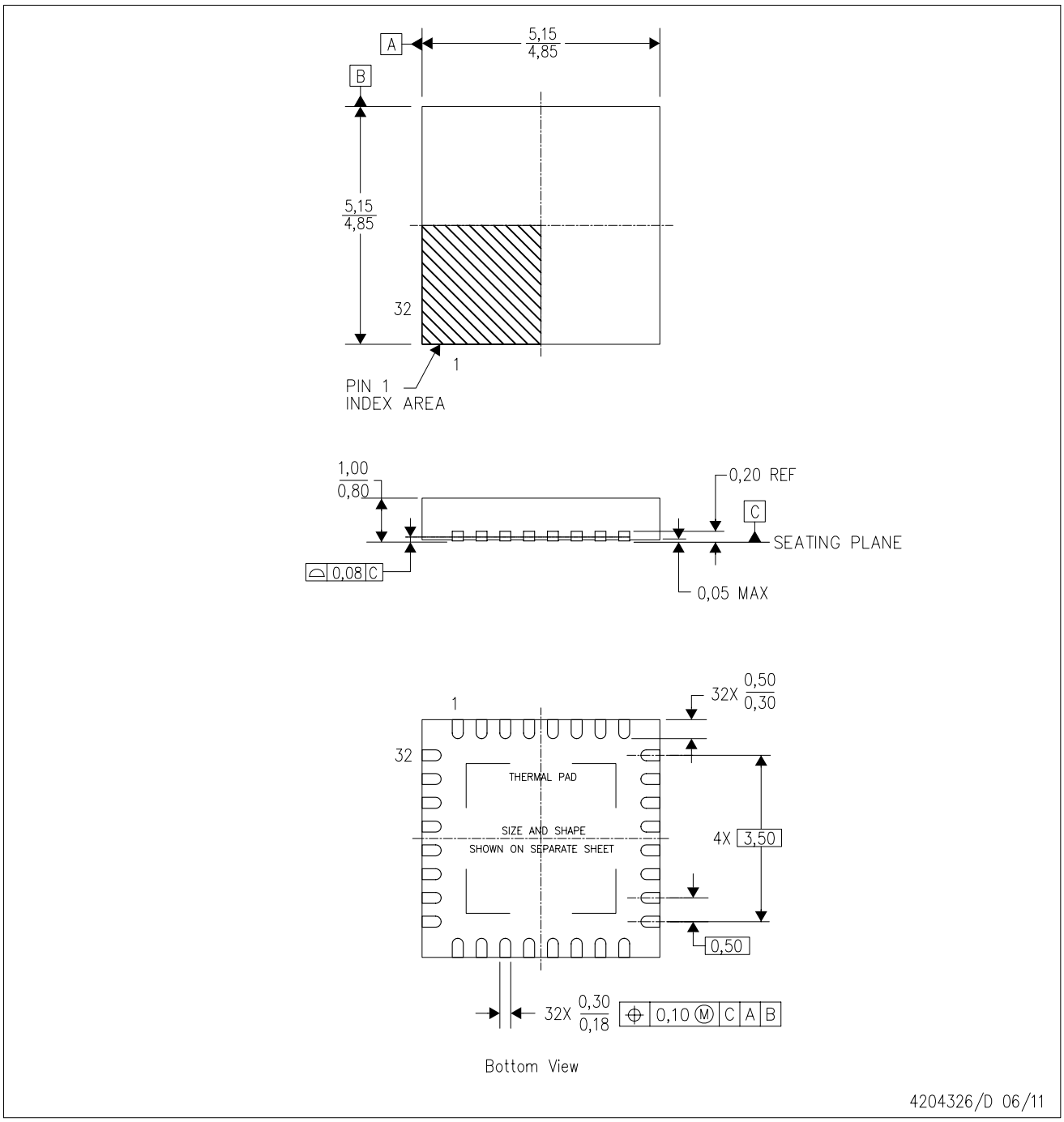
PLASTIC QUAD FLATPACK - NO LEAD



Images above are just a representation of the package family, actual package may vary.
Refer to the product data sheet for package details.

4224745/A

RHB (S–PVQFN–N32) PLASTIC QUAD FLATPACK NO–LEAD



NOTES:
A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M–1994.
B. This drawing is subject to change without notice.
C. QFN (Quad Flatpack No–Lead) Package configuration.
D. The package thermal pad must be soldered to the board for thermal and mechanical performance.
E. See the additional figure in the Product Data Sheet for details regarding the exposed thermal pad features and dimensions.
F. Falls within JEDEC MO–220.

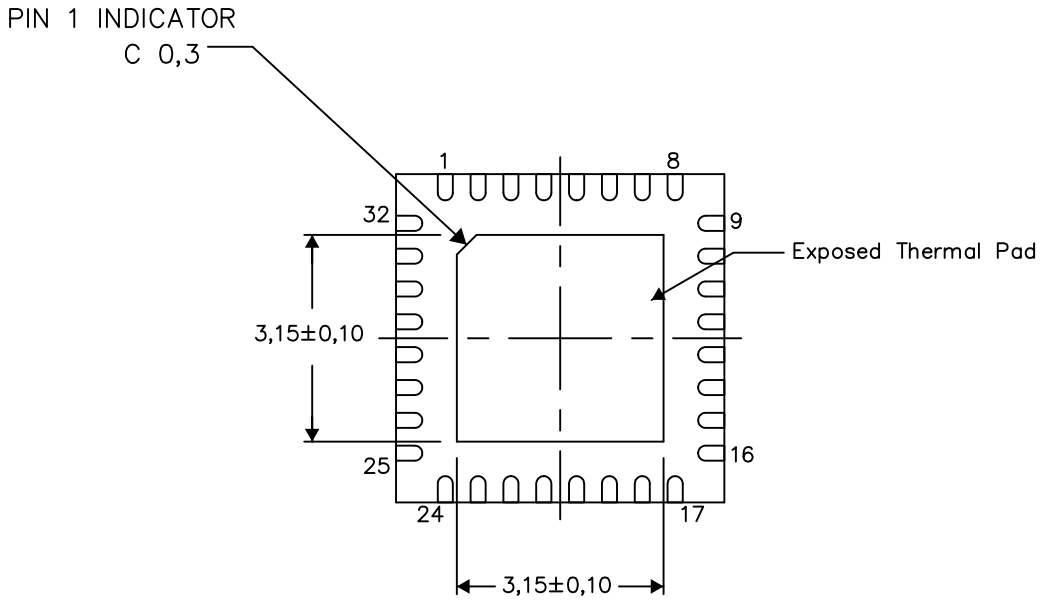
RHB (S–PVQFN–N32) PLASTIC QUAD FLATPACK NO–LEAD

THERMAL INFORMATION

This package incorporates an exposed thermal pad that is designed to be attached directly to an external heatsink. The thermal pad must be soldered directly to the printed circuit board (PCB). After soldering, the PCB can be used as a heatsink. In addition, through the use of thermal vias, the thermal pad can be attached directly to the appropriate copper plane shown in the electrical schematic for the device, or alternatively, can be attached to a special heatsink structure designed into the PCB. This design optimizes the heat transfer from the integrated circuit (IC).

For information on the Quad Flatpack No–Lead (QFN) package and its advantages, refer to Application Report, QFN/SON PCB Attachment, Texas Instruments Literature No. SLUA271. This document is available at www.ti.com.

The exposed thermal pad dimensions for this package are shown in the following illustration.



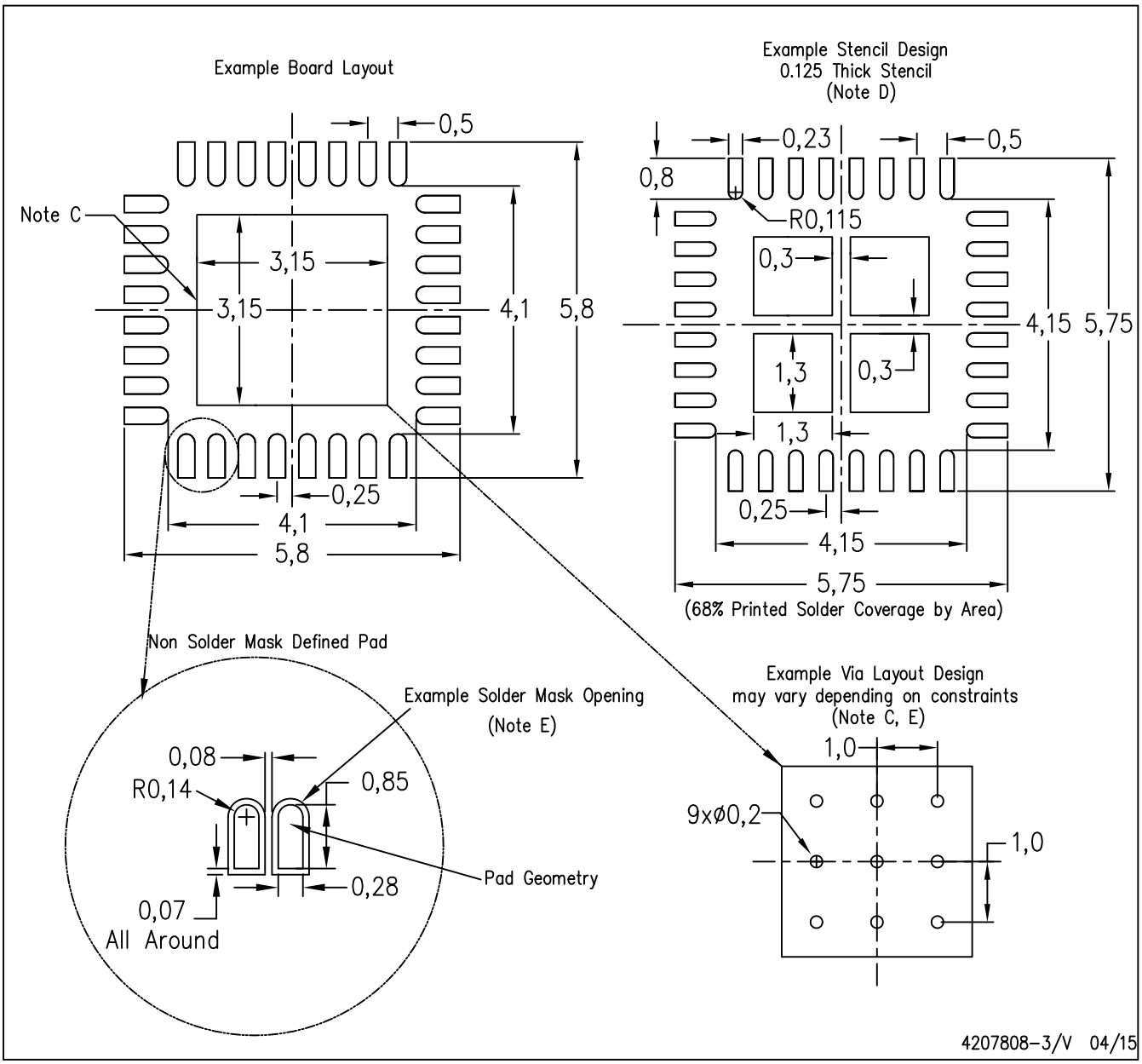
Bottom View

Exposed Thermal Pad Dimensions

4206356–3/AC 05/15

NOTE: A. All linear dimensions are in millimeters

RHB (S–PVQFN–N32) PLASTIC QUAD FLATPACK NO–LEAD



NOTES:
A. All linear dimensions are in millimeters.
B. This drawing is subject to change without notice.
C. This package is designed to be soldered to a thermal pad on the board. Refer to Application Note, Quad Flat–Pack Packages, Texas Instruments Literature No. SLUA271, and also the Product Data Sheets for specific thermal information, via requirements, and recommended board layout. These documents are available at www.ti.com <http://www.ti.com>.
D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC 7525 for stencil design considerations.
E. Customers should contact their board fabrication site for recommended solder mask tolerances and via tenting recommendations for any larger diameter vias placed in the thermal pad.

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